

Table of Contents

Preface

Nanocrystal Non-Volatile Memory Devices

Z.J. Horváth and P. Basa 1

On Similar Electrical, Optical and Structural Properties of MOS Structures Prepared on a-Si:H/c-Si, Porous Silicon/c-Si, and c-Si

E. Pinčík, H. Kobayashi, R. Brunner, M. Takahashi, J. Rusnák and M. Jergel 11

Sm_{1-x}Nd_xNiO₃ Thin Films Deposition by KrF Laser Ablation

S. Lafane, T. Kerdja, S. Abdelli-Messaci, S. Malek and M. Maaza 27

Problems with Synthesis of Chalcopyrite CuIn_{1-x}B_xSe₂

J. Olejníček, S.A. Darveau, C.L. Exstrom, R.J. Soukup, N.J. Ianno, C.A. Kamler and J. Huguenin-Love 33

Phase Explosion in Silicon and Titanium Targets Irradiated by Third Harmonic Nd-YAG Pulsed Laser

T. Kerdja, K. Yahiaoui, A. Bendib and S. Malek 37

Optical Properties of the Strained Layer Superlattices (GaAs)₆/(GaP)_m(001) (m=2, 4 and 6)

A. Hamidani and B. Bennecer 41

Characterization of a-C:H Thin Films Deposited from C₂H₄ by PECVD Microwave Discharge

M. Kihel, R. Clergeraux, S. Sahli, D. Escaich, Y. Segui and P. Raynaud 49

Thin Layered Structures Analysis Using NUR Reflectometer

M. Izerrouken 53

Characterization of SiOF Thin Films Deposited by PECVD from Hexamethyldisiloxane in Mixture with Oxygen and CF₄

R. Chabane, S. Sahli, A. Zenasni, P. Raynaud and Y. Segui 59

Cyclohexyl Methacrylate with Tetra (Ethylene Glycol) Dimethacrylate in Tertahydrofuran Radical Copolymerization

A. Fasla, S. Ould Kada, Z. Seghier and A. Périchaud 63

Water Molecule Sensitive Layers Deposited from Hexamethyldisiloxane/Oxygen Mixture at Low Temperature

N. Guermat, A. Bellel, S. Sahli, Y. Segui and P. Raynaud 69

Synthesis and Characterization of New Chelating Resin Functionalized with Pyrocatechol Violet and its Application as Extractant for Zinc (II)

T. Belaid, S. Aitali, M. Benamor and K. Belhamel 75

Effects of Hydrogen Partial Pressure on Boron-Doped Hydrogenated Amorphous Silicon (a-Si:H(B)) Properties

N. Khelifati, R. Cherfi, A. Keffous, A. Rahal and M. Kechouane 81

Structural Properties of Al-Cu Thin Films after Heat Treatment

S. Lallouche and M.Y. Debili 87

Comparative Study between Two Polymers of Arylene-Vinylene Units: Electrochemical, Spectroscopic Characterization and Resistivity Measurements

S. Mosbah, I. Zbiri and L. Bencharif 95

Space Resolved Optical Emission Spectroscopy During Deposition of Ba_xSr_{1-x}TiO₃ Thin Films by Double Hollow Cathode Plasma Jet System

J. Olejníček, Z. Hubička, M. Čada, P. Virostko, Š. Kment, P. Adámek, L. Jastrabik and A. Dejneka 105

Photoluminescence and Structural Properties of ZnO Films Deposited on Si Substrates by Chemical Spray Deposition

S. Sali, R. Tala-Ighil, S. Kermadi, M. Boumaour and M. Kechouane 111

Deposition of Titanium Nitride Thin Films onto Silicon by RF Reactive Magnetron Sputtering

N. Saoula, K. Henda and R. Kesri 117

Investigation of Deep Interface Traps in Very-Thin Oxide/Si Structures Prepared at Low Temperatures Using Chemical Solutions

J. Rusnák, M. Ružinský, K. Imamura, T. Matsumoto, M. Štefečka, M. Takahashi, H. Kobayashi and E. Pinčík 123

Correlation between Physicochemical and Electrical Properties of Hydrogenated Amorphous Silicon Doped with Boron: Effect of Thermal Annealing H.Y. Seba, R. Cherfi, F. Hamadache and M. Aoucher	129
Properties of ZnO Thin Films Grown on Si Substrates by Ultrasonic Spray and ZnO/Si Heterojunctions N. Zebbar, M.S. Aida, A.E.K. Hafdallah, O. Daranfad, H. Lekiket and M. Kechouane	133
Formation of Rough TiO₂ Thin Films on Glass and Porous Silicon by Sol-Gel Method N. Benzekkour, F.Z. Ghomrani, N. Gabouze, S. Kermadi, M. Boumaour and K. Ferdjani	139
Study of Unsupported and Al₂O₃ or SiO₂-Supported Nickel Molybdate for Oxireforming of Ethane H. Boukhlof, R. Benrabaa, S. Barama and A. Barama	145
Effect of the Electrode Geometry on the Diffusion-Current Problem of the Rotating Porous Silicon Electrode in HF Solution R. Cheggou, N. Gabouze and A. Kadoun	149
Characterization of Thin Layer SnO₂/Glass by Neutrons Reflectometry M.F. Khelladi, M. Izerrouken, S. Kermadi, R. Tala-Ighil, S. Sali and M. Boumaour	155
Study of the On-Surface Diffusion of the Ternary System Au/Pd/Si (111) A.H. Hammoudi, C. Benazzouz, S. Tobbeche, N. Benouattas and N. Boukhalifa	161
Ab Initio Calculation of Electronic Structure and Magnetic Properties of Rare Earth Nitride Using LDA+U Approach: EuN and GaEuN N. Kanoun-Bouayed, S. Goumri Said, A.E. Merad and M.B. Kanoun	167
Thallium Based Superconducting Thin Films Synthesized by RF-Sputtering and <i>Ex Situ</i> Thallination T. Guerfi, S. Beauquis, P. Galez and M.F. Mosbah	173
Optimization of DLC/PS Antireflection Coating Properties for Multicrystalline Silicon Solar Cells K. Ait-Hamouda, A. Ababou and N. Gabouze	179
Preparation and Characterization of Microporous Membranes Prepared by Wet Phase Inversion. Application to Ni (II) Transport S. Bey, M.G. Bounomenna, M. Benamor and E. Drioli	183
Synthesis and Characterization of Cerium Oxide (CeO₂) Nanoparticles C. Benmouhoub, A. Kadri, N. Benbrahim and S. Hadji	189
Electrical Properties Dependent on Schottky Diode Pd/PSC-pSi(100) Based on Hydrocarbon Gas Sensor A. Keffous, M. Kechouane, T. Kerdja, Y. Belkacem, K. Bourenane, H. Menari, M. Maoudj and A. Boukezzata	195
Elaboration of Porous Silicon Multilayer Using Resistive p-Type Si O. Fellahi, T. Hadjersi and L. Guerbous	201
Electrodeposition of CoNiFe Alloys on n-Type Silicon G. Fortas, S. Sam, Z. Fekih and N. Gabouze	207
Electrical and Optical Behavior of Al₂O₃/Porous Silicon/Silicon Structures N. Gabouze and K. Ait-Hamouda	213
Sol-Gel Synthesis of SiO₂-TiO₂ Film as Antireflection Coating on Silicon for Photovoltaic Application S. Kermadi, N. Agoudjil, S. Sali, R. Tala-Ighil and M. Boumaour	221
Hydrogen Sensor: Effect of Palladium Thickness and Porous Structure of Silicon H. Lachenani, H. Cheraga, H. Menari and N. Gabouze	225
Properties of Pt-Assisted Electroless Etched Silicon in HF/Na₂S₂O₈ Solution N. Megouda, T. Hadjersi, O. El Kachai, R. Boukherroub and L. Guerbous	231
Effect of Chromium and Vanadium on Nanolayered Ternary Carbides: AB Initio Study A.E. Merad and M.B. Kanoun	239
Properties of CdS Thin Films Grown by Chemical Bath Deposition as a Function of Bath Temperature H. Moualkia, S. Hariech and M.S. Aida	243
Functionalization of ISE Sensor for Metal Ion Detection K. Morakchi, A. Zazoua, A. Hamel, S. Zougar, R. Kherrat and N. Jaffrezic-Renault	249
Adsorption of Dyes and Metal Ions by Acrylamide - Co - Acrylic Acid Hydrogels Synthesized by Gamma Radiation L. Aberkane-Mechebbek, S.F. Larbi-Youcef and M. Mahlous	255

A FET Gas Sensor Device Based on Porous Silicon N. Zouadi, N. Gabouze, D. Bradai and D. Dahmane	261
Characterization of CN_x Thin Films Synthesized by Laser Ablation Technique N. Zouadi, S. Abdelli-Messaci, N. Gabouze, T. Kerdja and D. Bradai	265
Morphological Characterization of Sacrificial Layers of Porous Silicon for Photovoltaic Application A. Ould-Abbas, M. Madani and N.E. Chabane Sari	269
On Topographic Properties of Semiconductor Surfaces and Thin Film Systems S. Jurečka, H. Kobayashi, M. Takahashi, R. Brunner, M. Madani and E. Pinčík	275
Photoluminescence of Passivated a-Si:H R. Brunner, H. Kobayashi, M. Kučera, M. Takahashi, J. Rusnák and E. Pinčík	281
Synthesis and Characterization of Porous Materials Containing Modified Cellulose by β-Cyclodextrin for the Application in Processing Industrial Liquid Waste D. Ghemati and D. Aliouche	287